Contribution ID: **31**

Type: **not specified**

First results of new p-type strip and pad detectors with LGAD in epitaxial wafers (remote, afternoon)

Wednesday 13 November 2013 15:40 (20 minutes)

In the framework of the RD50 collaboration new p-type devices with LGAD in epitaxial wafers and float zone wafers were fabricated in CNM. Here we present first results of strips and pad detectors.

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Session Classification: Detectors with Charge Multiplication